



PNP MEDIUM POWER TRANSISTORS IN SOT89

Features

- BV_{CEO} > -45V, -60V & -80V
- I_C = -1A Continuous Collector Current
- I_{CM} = -2A Peak Pulse Current
- Low Saturation Voltage V_{CE(SAT)} < -500mV @ -0.5A
- Gain Groups 10 and 16
- Complementary NPN Types: BCX54, 55 and 56
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Leads; Solderable per MIL-STD-202 Method 208 @3
- Weight: 0.052 grams (Approximate)

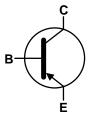
Applications

- Medium Power Switching or Amplification Applications
- AF Driver and Output Stages

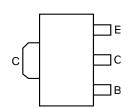








Device Symbol



Top View Pin-Out

Ordering Information (Notes 4 & 5)

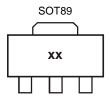
| Product | Compliance | Marking | Reel Size (inches) | Tape Width (mm) | Quantity per Reel |
|-------------|------------|--|--------------------|-----------------|-------------------|
| BCX51TA | AEC-Q101 | AA | 7 | 12 | 1,000 |
| BCX51-13R | AEC-Q101 | AA | 13 | 12 | 4,000 |
| BCX5110TA | AEC-Q101 | AC | 7 | 12 | 1,000 |
| BCX5116TA | AEC-Q101 | AD | 7 | 12 | 1,000 |
| BCX5116TC | AEC-Q101 | AD | 13 | 12 | 4,000 |
| BCX52TA | AEC-Q101 | AE | 7 | 12 | 1,000 |
| BCX5210TA | AEC-Q101 | AG | 7 | 12 | 1,000 |
| BCX5216TA | AEC-Q101 | AM | 7 | 12 | 1,000 |
| BCX5216QTA | Automotive | AM | 7 | 12 | 1,000 |
| BCX53TA | AEC-Q101 | AH | 7 | 12 | 1,000 |
| BCX5310TA | AEC-Q101 | AK | 7 | 12 | 1,000 |
| BCX5316TA | AEC-Q101 | AL | 7 | 12 | 1,000 |
| BCX5316TC | AEC-Q101 | AL | 13 | 12 | 4,000 |
| BCX5316-13R | AEC-Q101 | AL | 13 | 12 | 4,000 |
| BCX5110TC | AEC-Q101 | AC | 13 | 12 | 4,000 |
| BCX51TC | AEC-Q101 | AA | 13 | 12 | 4,000 |
| BCX5210TC | AEC-Q101 | AG | 13 | 12 | 4,000 |
| BCX5216TC | AEC-Q101 | AM | 13 | 12 | 4,000 |
| BCX52TC | AEC-Q101 | AE | 13 | 12 | 4,000 |
| BCX5310TC | AEC-Q101 | AK | 13 | 12 | 4,000 |
| BCX53TC | AEC-Q101 | AH | 13 | 12 | 4,000 |
| BCX5316QTA | Automotive | Refer to http://diodes.com/datasheets/BCX5316Q.pdf | | | |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.



Marking Information



xx = Product Type Marking Code, as follows:

 BCX51
 = AA
 BCX52
 = AE
 BCX53
 = AH

 BCX5110
 = AC
 BCX5210
 = AG
 BCX5310
 = AK

 BCX5116
 = AD
 BCX5216
 = AM
 BCX5316
 = AL

Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | BCX51 | BCX52 | BCX53 | Unit |
|------------------------------|------------------|-------|-------|-------|------|
| Collector-Base Voltage | V _{CBO} | -45 | -60 | -100 | V |
| Collector-Emitter Voltage | V _{CEO} | -45 | -60 | -80 | V |
| Emitter-Base Voltage | V _{EBO} | -5 | | V | |
| Continuous Collector Current | Ic | | -1 | | |
| Peak Pulse Collector Current | Ісм | -2 | | A | |
| Continuous Base Current | I _B | | -100 | | mA |
| Peak Pulse Base Current | I _{BM} | | -200 | | |

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | | |
|---|-----------------------------------|------------------|------|------|--|
| | (Note 6) | | 1 | | |
| Power Dissipation | (Note 7) | P _D | 1.5 | W | |
| | (Note 8) | | 2.0 | | |
| | (Note 6) | | 125 | | |
| Thermal Resistance, Junction to Ambient Air | (Note 7) | R _{0JA} | 83 | °C/W | |
| | (Note 8) | | 60 | | |
| Thermal Resistance, Junction to Lead | (Note 9) | $R_{\theta JL}$ | 13 | °C/W | |
| Operating and Storage Temperature Range | T _J , T _{STG} | -65 to +150 | °C | | |

ESD Ratings (Note 10)

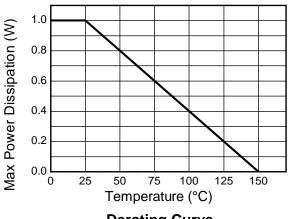
| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | 400 | V | С |

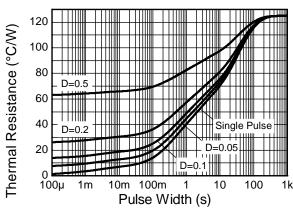
Notes:

- 6. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 7. Same as Note 6, except the device is mounted on 25mm x 25mm 1oz copper.
- 8. Same as Note 6, except the device is mounted on 50mm x 50mm 1oz copper.
- 9. Thermal resistance from junction to solder-point (on the exposed collector pad).
- 10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



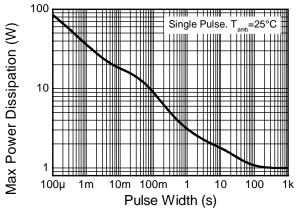
Thermal Characteristics and Derating Information



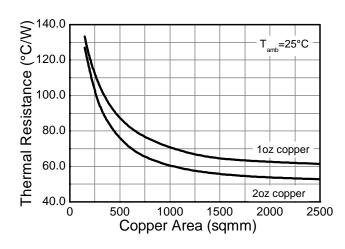


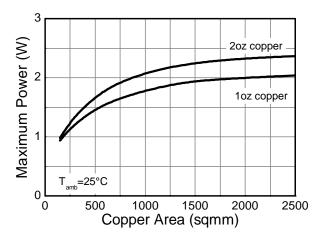
Derating Curve

Transient Thermal Impedance



Pulse Power Dissipation





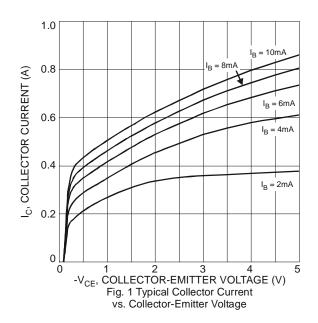


Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

| Characteristic | | Symbol | Min | Тур | Max | Unit | Test Condition |
|---|--------------|----------------------|------|-----|------|------|--|
| Callaster Dage | BCX51 | | -45 | _ | _ | V | I _C = -100μA |
| Collector-Base Breakdown Voltage | BCX52 | BV _{CBO} | -60 | | | | |
| Dicardown Voltage | BCX53 | | -100 | | | | |
| Callastan Fraittan | BCX51 | | -45 | _ | _ | | |
| Collector-Emitter Breakdown Voltage (Note 11) | BCX52 | BV _{CEO} | -60 | | | V | $I_C = -10mA$ |
| breakdown voltage (Note 11) | BCX53 | | -80 | | | | |
| Emitter-Base Breakdown Voltage | | BV _{EBO} | -5 | _ | _ | V | I _E = -10μA |
| Outlies to a Out Off Ourseld | | | | | -0.1 | | V _{CB} = -30V |
| Collector Cut-Off Current | | I _{CBO} | _ | _ | -20 | μΑ | $V_{CB} = -30V, T_J = +150$ °C |
| Emitter Cut-Off Current | | I _{EBO} | _ | _ | -20 | nA | $V_{EB} = -5V$ |
| | All versions | h _{FE} | 25 | _ | _ | _ | $I_C = -5mA$, $V_{CE} = -2V$ |
| | | | 40 | _ | 250 | | $I_C = -150 \text{mA}, V_{CE} = -2 \text{V}$ |
| Static Forward Current Transfer Ratio (Note 11) | | | 25 | _ | _ | | $I_C = -500 \text{mA}, V_{CE} = -2 \text{V}$ |
| (Note 11) | 10 gain grp | | 63 | _ | 160 | | $I_C = -150 \text{mA}, V_{CE} = -2 \text{V}$ |
| | 16 gain grp | | 100 | _ | 250 | | $I_C = -150 \text{mA}, V_{CE} = -2 \text{V}$ |
| Collector-Emitter Saturation Voltage (Note 11) | | V _{CE(sat)} | _ | _ | -0.5 | V | $I_C = -500 \text{mA}, I_B = -50 \text{mA}$ |
| Base-Emitter Turn-On Voltage (Note 11) | | V _{BE(on)} | _ | _ | -1.0 | V | $I_C = -500 \text{mA}, V_{CE} = -2 \text{V}$ |
| Transition Frequency | | f⊤ | 150 | _ | _ | MHz | $I_C = -50 \text{mA}, V_{CE} = -10 \text{V}$ f = 100MHz |
| Output Capacitance | | Cobo | _ | | 25 | pF | $V_{CB} = -10V$, $f = 1MHz$ |

Note:

^{11.} Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.



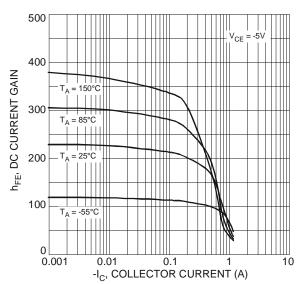


Fig. 2 Typical DC Current Gain vs. Collector Current



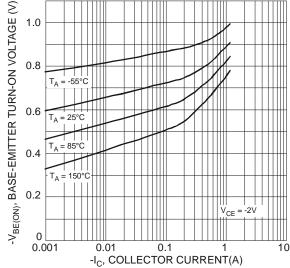


Fig 3 Typical Base-Emitter Turn-On Voltage vs. Collector Current

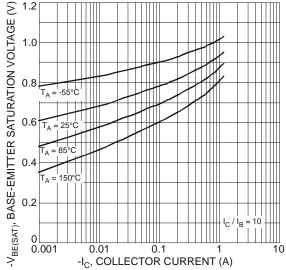


Fig. 5 Typical Base-Emitter Saturation Voltage vs. Collector Current

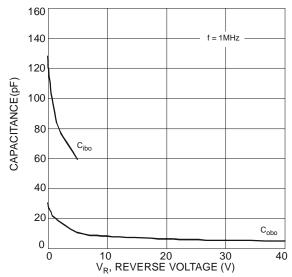


Fig. 7 Typical Capacitance Characteristics

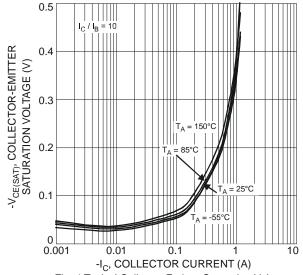


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

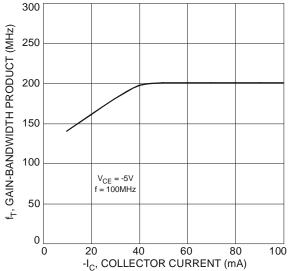
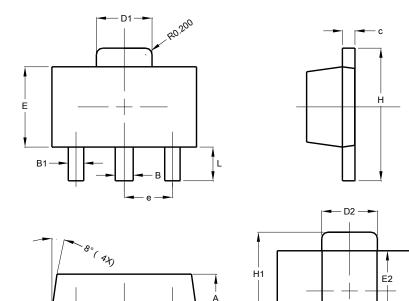


Fig. 6 Typical Gain-Bandwidth Product vs. Collector Current



Package Outline Dimensions

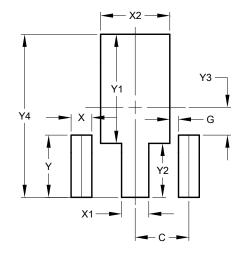
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



| SOT89 | | | | | |
|----------------------|-------|-------|-------|--|--|
| Dim | Min | Max | Тур | | |
| Α | 1.40 | 1.60 | 1.50 | | |
| В | 0.50 | 0.62 | 0.56 | | |
| B1 | 0.42 | 0.54 | 0.48 | | |
| С | 0.35 | 0.43 | 0.38 | | |
| D | 4.40 | 4.60 | 4.50 | | |
| D1 | 1.62 | 1.83 | 1.733 | | |
| D2 | 1.61 | 1.81 | 1.71 | | |
| Е | 2.40 | 2.60 | 2.50 | | |
| E2 | 2.05 | 2.35 | 2.20 | | |
| е | - | - | 1.50 | | |
| Н | 3.95 | 4.25 | 4.10 | | |
| H1 | 2.63 | 2.93 | 2.78 | | |
| L | 0.90 | 1.20 | 1.05 | | |
| L1 | 0.327 | 0.527 | 0.427 | | |
| Z | 0.20 | 0.40 | 0.30 | | |
| All Dimensions in mm | | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | (in mm) |
|------------|---------|
| C | 1.500 |
| G | 0.244 |
| Х | 0.580 |
| X1 | 0.760 |
| X2 | 1.933 |
| Υ | 1.730 |
| Y1 | 3.030 |
| Y2 | 1.500 |
| Y3 | 0.770 |
| Y4 | 4.530 |

Value



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